

# TLP3109A

## 1. Applications

- Mechanical relay replacements
- Heating, ventilation and air conditioning (HVAC)
- Security Systems
- Factory Automation (FA)
- I/O Interface Boards
- Measuring Instruments

## 2. General

The TOSHIBA TLP3109A photorelay consists of a photo MOSFET optically coupled to an infrared LED. It is housed in a 2.54SOP6 package. The low ON-state resistance and the high permissible ON-state current of the TLP3109A make it suitable for power line control applications.

## 3. Features

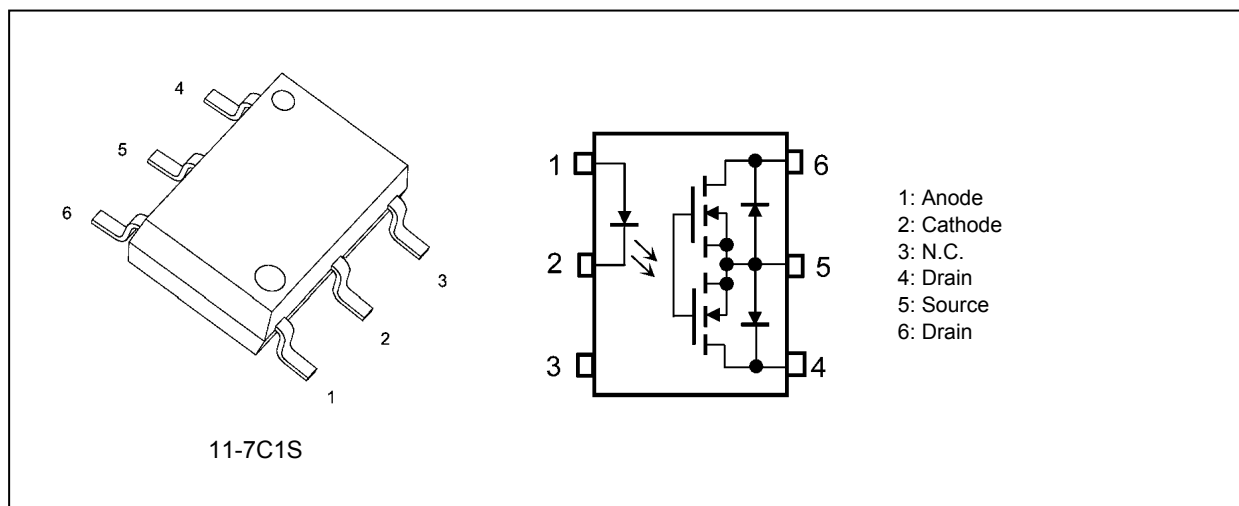
- (1) Normally opened (1-Form-A)
- (2) OFF-state output terminal voltage: 100 V (min)
- (3) Trigger LED current: 3 mA (max)
- (4) ON-state current: 3 A (max) (A connection)
- (5) ON-state resistance: 65 mΩ (max) (A connection)
- (6) Isolation voltage: 1500 Vrms (min)
- (7) Safety standards

UL-recognized: UL 1577, File No.E67349

VDE-approved: EN 60747-5-5 (**Note 1**)

Note 1: When a VDE approved type is needed, please designate the **Option (V4)**.

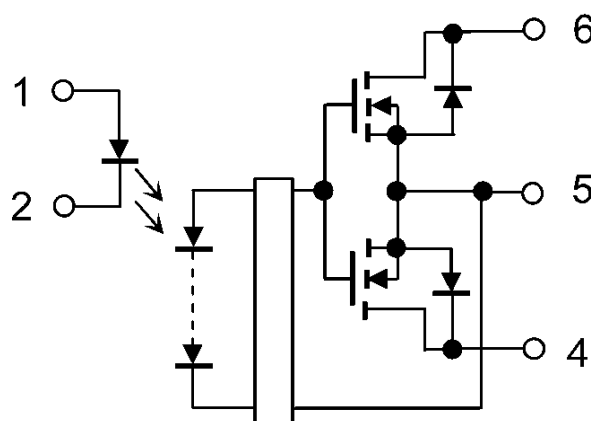
## 4. Packaging and Pin Assignment



Start of commercial production

2019-03

## 5. Internal Circuit



## 6. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$ )

	Characteristics	Symbol	Note	Rating	Unit
LED	Input forward current	$I_F$		30	mA
	Input forward current derating ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta I_F / \Delta T_a$		-0.3	mA/ $^{\circ}\text{C}$
	Input forward current (pulsed) (100 $\mu\text{s}$ pulse, 100 pps)	$I_{FP}$		1	A
	Input reverse voltage	$V_R$		6	V
	Input power dissipation	$P_D$		50	mW
	Input power dissipation derating ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta P_D / \Delta T_a$		-0.5	mW/ $^{\circ}\text{C}$
	Junction temperature	$T_j$		125	$^{\circ}\text{C}$
Detector	OFF-state output terminal voltage	$V_{OFF}$		100	V
	ON-state current (A connection)	$I_{ON}$	(Note 1)	3	A
	ON-state current (B connection)	$I_{ON}$	(Note 1)	3	
	ON-state current (C connection)	$I_{ON}$	(Note 1)	6	
	ON-state current derating (A connection) ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta I_{ON} / \Delta T_a$	(Note 1)	-30	mA/ $^{\circ}\text{C}$
	ON-state current derating (B connection) ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta I_{ON} / \Delta T_a$	(Note 1)	-30	
	ON-state current derating (C connection) ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta I_{ON} / \Delta T_a$	(Note 1)	-60	
	ON-state current (pulsed) ( $t = 100\text{ ms}$ , Duty = 1/10)	$I_{ONP}$		9	A
	Output power dissipation	$P_O$		400	mW
	Output power dissipation derating ( $T_a \geq 25\text{ }^{\circ}\text{C}$ )	$\Delta P_O / \Delta T_a$		-4.0	mW/ $^{\circ}\text{C}$
	Junction temperature	$T_j$		125	$^{\circ}\text{C}$
Common	Storage temperature	$T_{stg}$		-55 to 125	$^{\circ}\text{C}$
	Operating temperature	$T_{opr}$		-40 to 110	
	Lead soldering temperature (10 s)	$T_{sol}$		260	
	Isolation voltage (AC, 60 s, R.H. $\leq 60\%$ )	$BV_S$	(Note 2)	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: For an application circuit example, see Chapter 12.2.

Note 2: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

## 7. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Typ.	Max	Unit
Supply voltage	$V_{DD}$		—	—	80	V
Input forward current	$I_F$		5	10	25	mA
ON-state current	$I_{ON}$		—	—	3	A
Operating temperature	$T_{opr}$		-20	—	85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

## 8. Electrical Characteristics (Unless otherwise specified, $T_a = 25\text{ °C}$ )

	Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
LED	Input forward voltage	$V_F$		$I_F = 10\text{ mA}$	1.50	1.65	1.80	V
	Input reverse current	$I_R$		$V_R = 5\text{ V}$	—	—	10	μA
	Input capacitance	$C_t$		$V = 0\text{ V}$ , $f = 1\text{ MHz}$	—	70	—	pF
Detector	OFF-state current	$I_{OFF}$		$V_{OFF} = 100\text{ V}$	—	—	1	μA
	Output capacitance	$C_{OFF}$		$V = 0\text{ V}$ , $f = 1\text{ MHz}$	—	460	—	pF

## 9. Coupled Electrical Characteristics (Unless otherwise specified, $T_a = 25\text{ °C}$ )

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	$I_{FT}$		$I_{ON} = 1\text{ A}$	—	0.35	3	mA
Return LED current	$I_{FC}$		$I_{OFF} = 10\text{ μA}$	0.1	0.2	—	
ON-state resistance (A connection)	$R_{ON}$	(Note 1)	$I_F = 5\text{ mA}$ , $I_{ON} = 3\text{ A}$ , $t < 1\text{ s}$	—	50	65	mΩ
ON-state resistance (B connection)				—	25	33	
ON-state resistance (C connection)			$I_F = 5\text{ mA}$ , $I_{ON} = 6\text{ A}$ , $t < 1\text{ s}$	—	13	16	

Note 1: For an application circuit example, see Chapter 12.2.

## 10. Isolation Characteristics (Unless otherwise specified, $T_a = 25\text{ °C}$ )

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Total capacitance (input to output)	$C_S$	(Note 1)	$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$	—	0.8	—	pF
Isolation resistance	$R_S$	(Note 1)	$V_S = 500\text{ V}$ , R.H. $\leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	Ω
Isolation voltage	$BV_S$	(Note 1)	AC, 60 s	1500	—	—	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

11. Switching Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^{\circ}\text{C}$ )

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Turn-on time	$t_{ON}$		See Fig. 11.1. $I_F = 5\text{ mA}$ , $V_{DD} = 20\text{ V}$ , $R_L = 200\text{ }\Omega$	—	0.45	2	ms
Turn-off time	$t_{OFF}$		See Fig. 11.1. $I_F = 5\text{ mA}$ , $V_{DD} = 20\text{ V}$ , $R_L = 200\text{ }\Omega$	—	0.1	0.5	

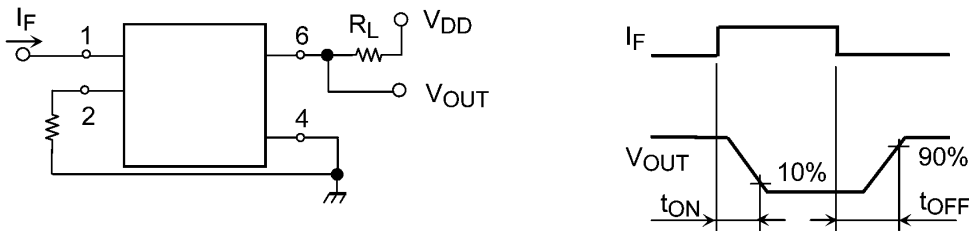


Fig. 11.1 Switching Time Test Circuit and Waveform

## 12. Characteristics Curves and Circuit Connections

### 12.1. Characteristics Curves (Note)

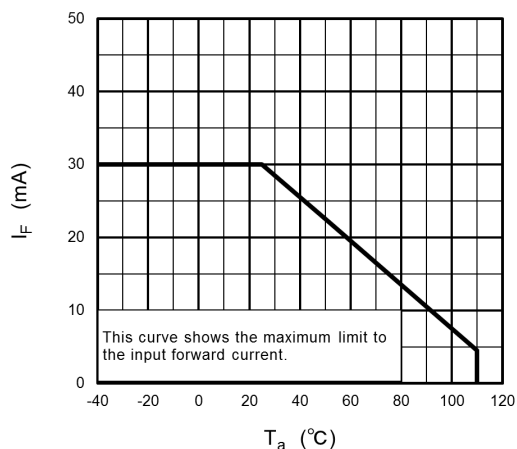


Fig. 12.1.1  $I_F - T_a$

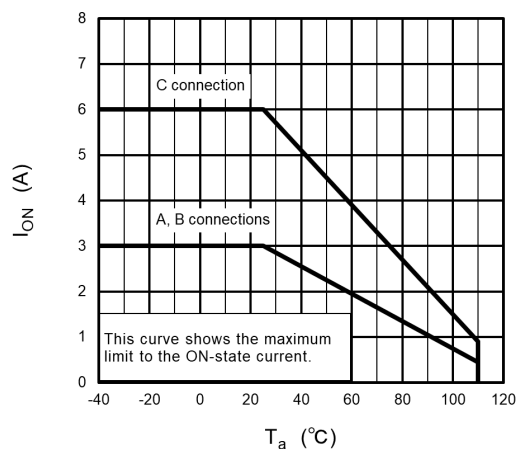


Fig. 12.1.2  $I_{ON} - T_a$

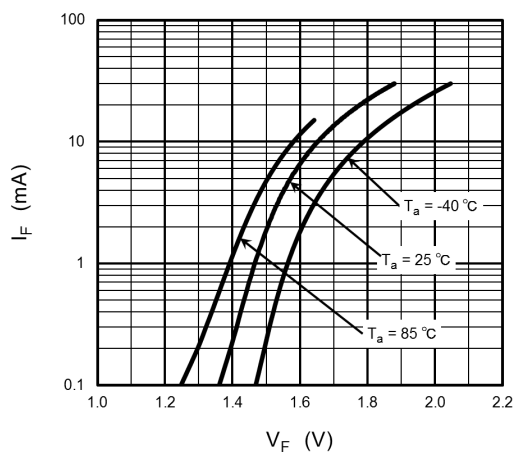


Fig. 12.1.3  $I_F - V_F$

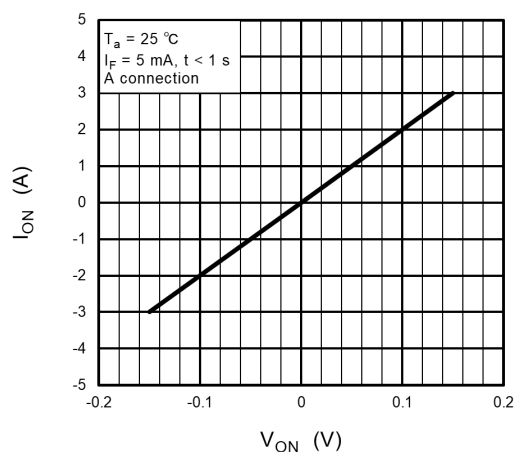


Fig. 12.1.4  $I_{ON} - V_{ON}$

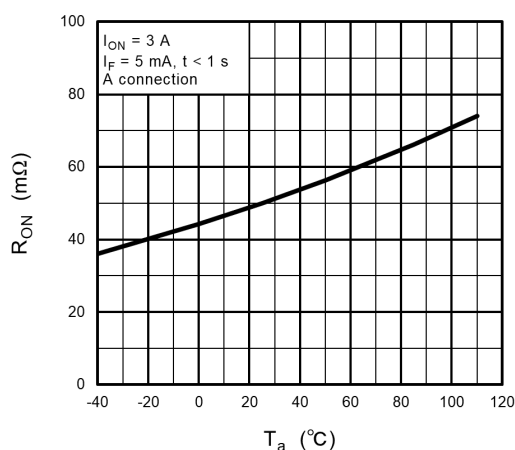


Fig. 12.1.5  $R_{ON} - T_a$

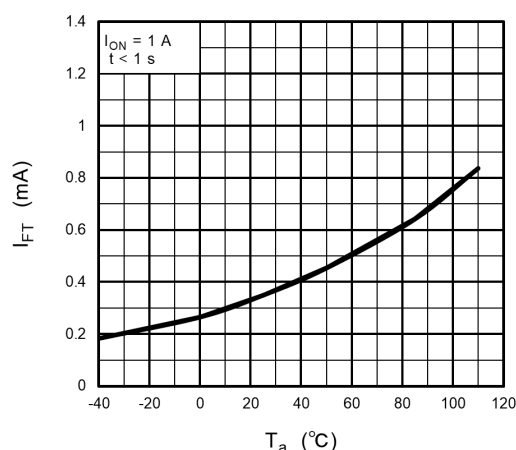
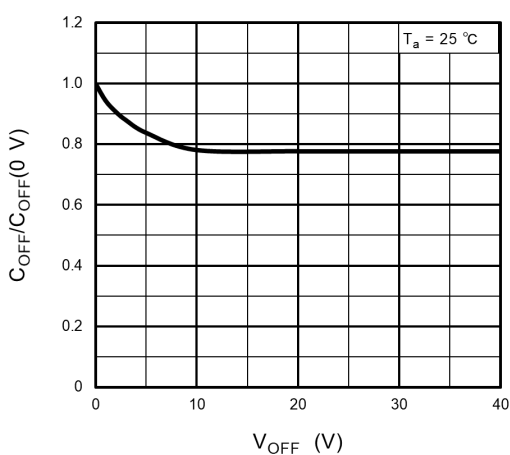
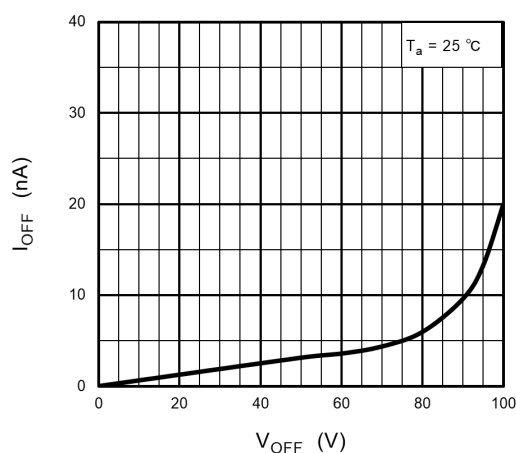
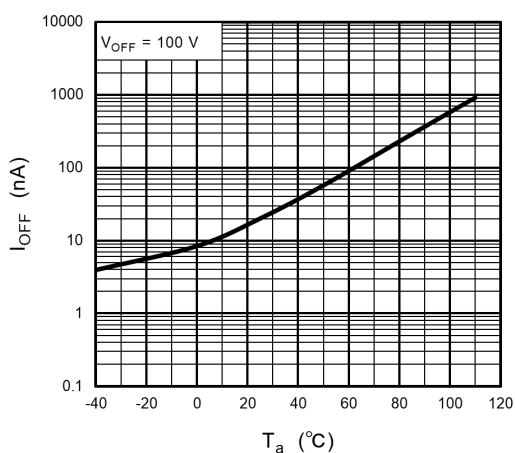
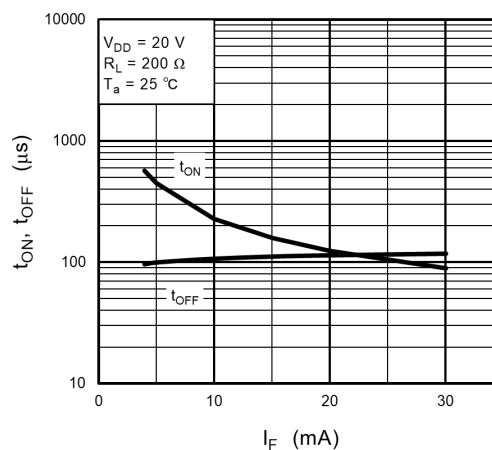
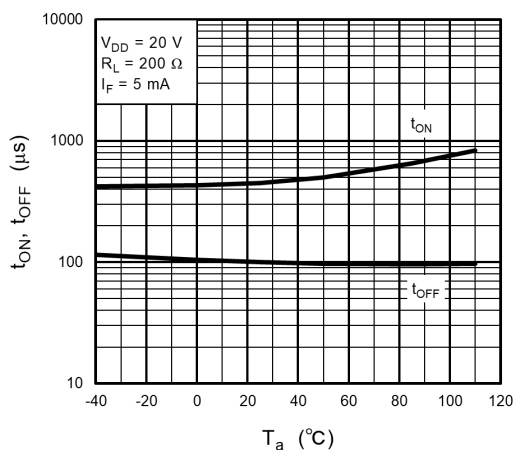


Fig. 12.1.6  $I_{FT} - T_a$



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## 12.2. Circuit Connections

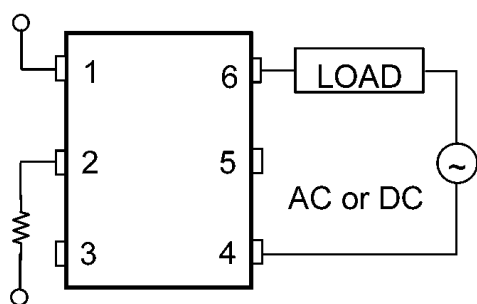


Fig. 12.2.1 A Connection

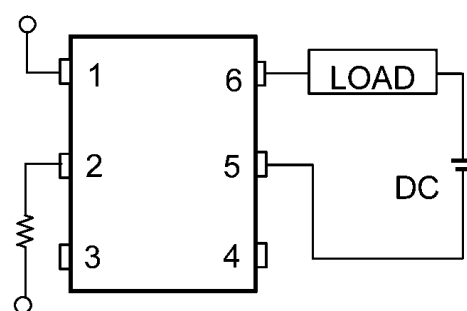


Fig. 12.2.2 B Connection

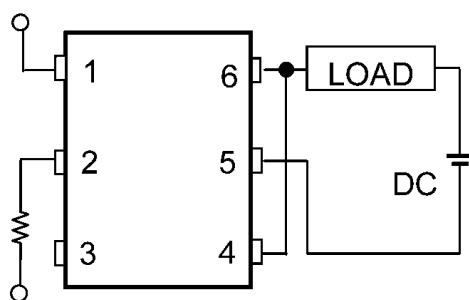


Fig. 12.2.3 C Connection

## 13. Soldering and Storage

### 13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

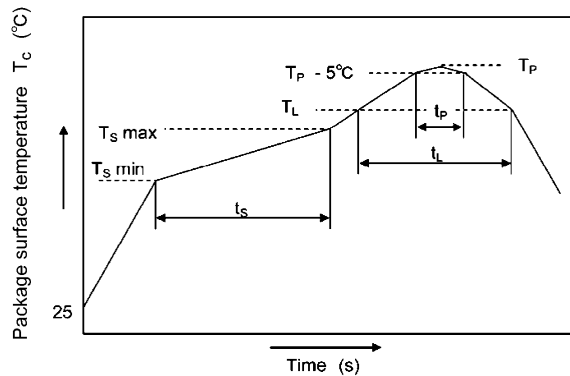
- When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	$T_S$	150	200	°C
Preheat time	$t_S$	60	120	s
Ramp-up rate ( $T_L$ to $T_P$ )			3	°C/s
Liquidus temperature	$T_L$	217		°C
Time above $T_L$	$t_L$	60	150	s
Peak temperature	$T_P$		260	°C
Time during which $T_c$ is between ( $T_P - 5$ ) and $T_P$	$t_P$		30	s
Ramp-down rate ( $T_P$ to $T_L$ )			6	°C/s

An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

- When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.

Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

- When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

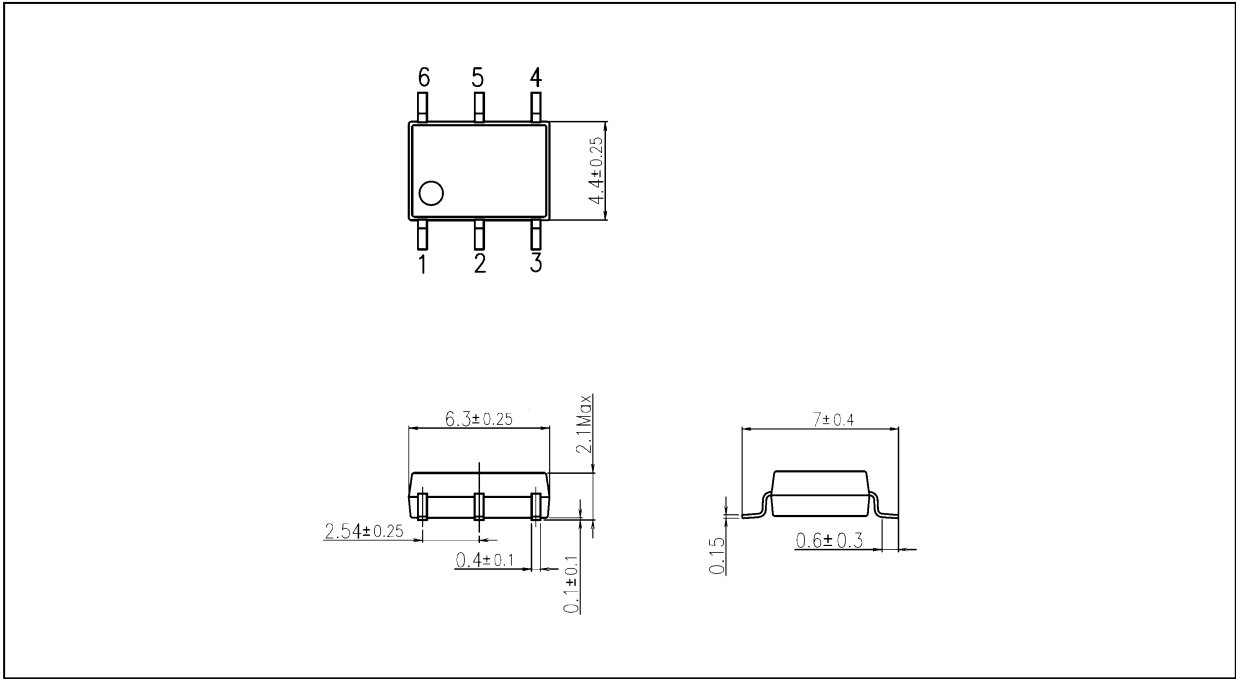
### 13.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



Package Dimensions

Unit: mm



Weight: 0.13 g (typ.)

Package Name(s)
TOSHIBA: 11-7C1S

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